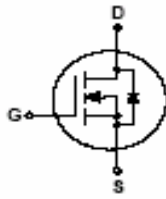
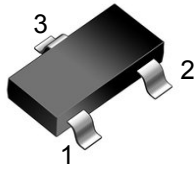



SOT-23

MARKING: S6

Features

Advanced trench process technology
 High density cell design for Ultra Low On-Resistance
 Halogen free and RoHS compliant

Mechanical Data

SOT-23 Small Outline Plastic Package
 EpoxyUL:94V-0

Maximum Ratings & Thermal Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

Symbol	Parameter	Rating	Unit	
V _{DS}	Drain-Source Breakdown Voltage	30	V	
V _{GS}	Gate-Source Voltage	±20	V	
T _J	Maximum Junction Temperature	150	°C	
T _{STG}	Storage Temperature Range	-55 to 150	°C	
I _S	Diode Continuous Forward Current	T _c =25°C	4	A
I _{DM}	Pulse Drain Current Tested	T _c =25°C	15	A
I _D	Continuous Drain Current@GS=10V	T _c =25°C	4	A
P _D	Maximum Power Dissipation	T _c =25°C	1	W
R _{θJA}	Thermal Resistance Junction-Ambient>(*1 in2 Pad of 2-oz Copper), Max.)	125	°C/W	

Electrical Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	30	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =30V, V _{GS} =0V	--	--	1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1	1.5	2.2	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =4A	--	32	50	mΩ
		V _{GS} =4.5V, I _D =3A	--	41	60	

Dynamic Electrical Characteristics

C _{ISS}	Input Capacitance	V _{DS} =15V, V _{GS} =0V, f=1MHz	--	275	--	pF
C _{OSS}	Output Capacitance		--	43	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	33	--	pF

Switching Characteristics

Q _g	Total Gate Charge	V _{DS} =15V, I _D =4A, V _{GS} =10V	--	6.6	--	nC
Q _{gs}	Gate Source Charge		--	1.4	--	nC
Q _{gd}	Gate Drain Charge		--	2	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =15V, R _L =3.6Ω, V _{GS} =4.5V, R _G =6Ω	--	3.3	--	nS
t _r	Turn-on Rise Time		--	14.8	--	nS
t _{d(off)}	Turn-Off Delay Time		--	12	--	nS
t _f	Turn-Off Fall Time		--	3.1	--	nS

Source- Drain Diode Characteristics

V _{SD}	Forward on voltage	T _j =25°C, I _s =4A,	--	--	1.2	V
-----------------	--------------------	---	----	----	-----	---

Ratings and Characteristic Curves

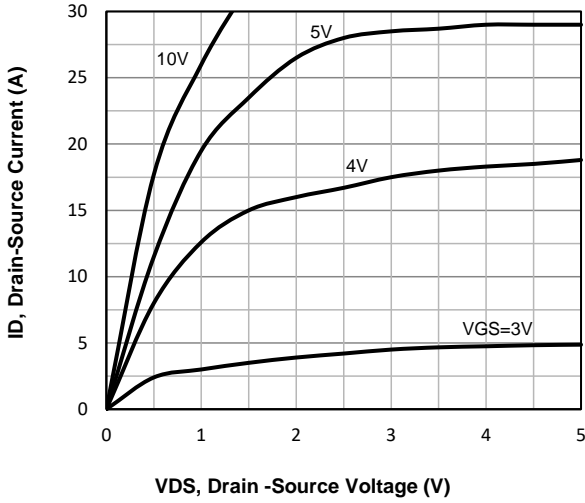


Fig1. Typical Output Characteristics

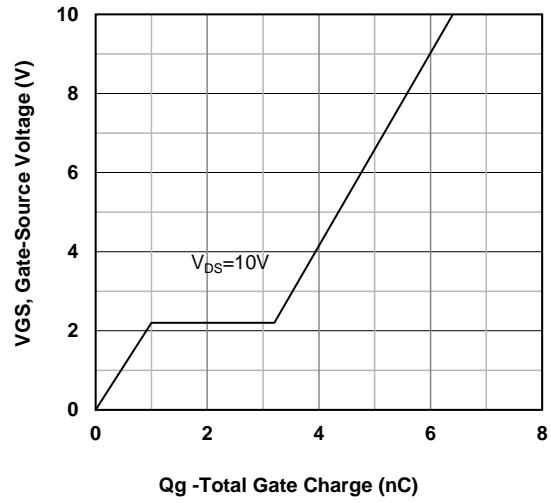


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

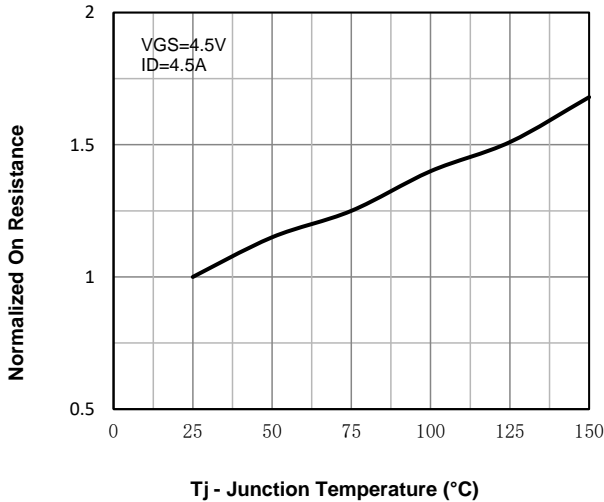


Fig3. Normalized On-Resistance Vs. Temperature

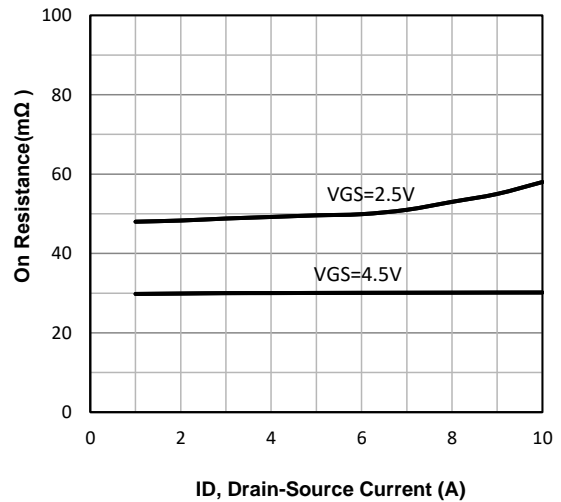


Fig4. On-Resistance Vs. Drain-Source Current

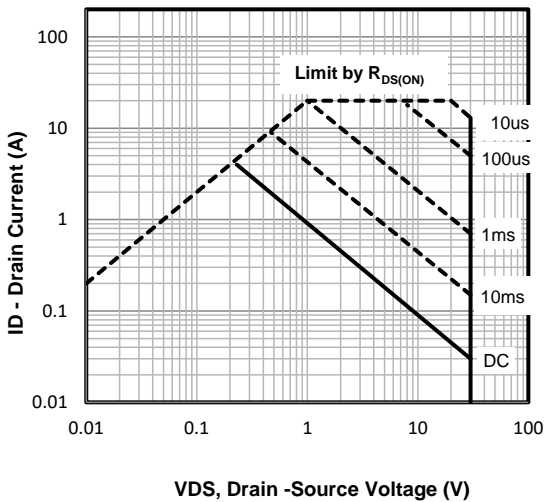


Fig5. Maximum Safe Operating Area

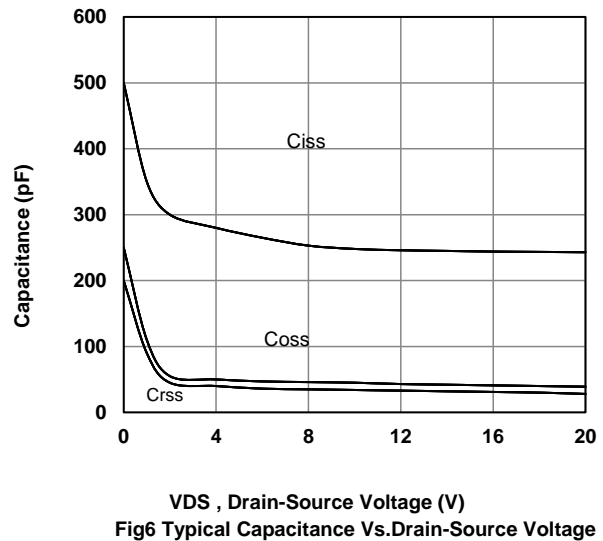
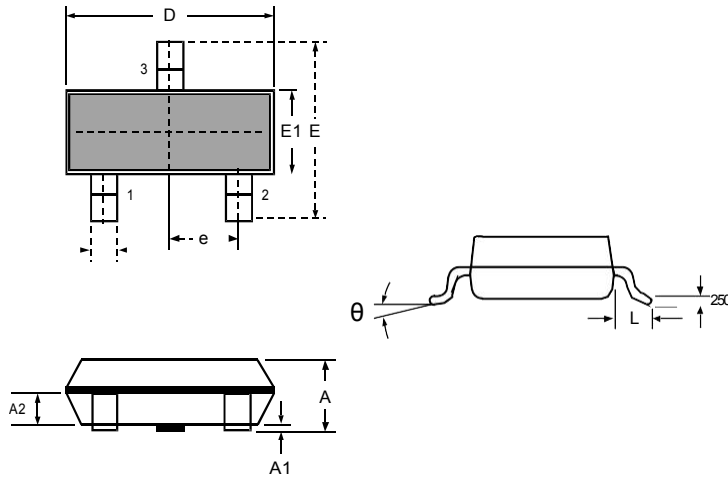


Fig6 Typical Capacitance Vs. Drain-Source Voltage

Summary of Packing Options

Package	Packing Description	Packing Quantity	Industry Standard
SOT-23	Tape/Reel, 7" reel	3000	EIA-481-1

Package Outline Dimensions: SOT-23



DIMENSIONS

SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
D	2.800	3.000	0.110	0.118
b	0.300	0.500	0.012	0.020
E	2.250	2.550	0.089	0.100
E1	1.200	1.400	0.047	0.055
e	0.950 BSC		0.037 BSC	
L	0.300	0.500	0.012	0.020
θ	0	8°	0	8°